

(Use several sheets if necessary)

Applicant: Shunpei YAMAZAKI et al.

Filing Date: August 21, 2001

Group: 281

Examiner Initial	Document Number	Date	Name	Class	Subclass	Filing Date (if appropriate)
JS	5,612,250	03/18/1997	Ohtani et al.			
JS	5,543,352	08/06/1996	Ohtani et al.			
JS	5,895,933	04/20/1999	Zhang et al.			
JS	5,882,960	03/16/1999	Zhang et al.			
JS	6,051,453	04/18/2000	Takemura			
JS	5,953,597	09/14/1999	Kusumoto et al.			
JS	5,561,081	10/01/1996	Takenouchi et al.			
JS	5,897,799	04/27/1999	Yamazaki et al.			
JS	6,002,101	12/14/1999	Yamazaki et al.			
JS	5,968,383	10/19/1999	Yamazaki et al.			
JS	5,900,980	05/04/1999	Yamazaki et al.			
JS	6,038,075	03/14/2000	Yamazaki et al.			
JS	5,959,779	09/28/1999	Yamazaki et al.			
JS	6,002,523	12/14/1999	Tanaka			

	Document Number	Date	Country	Class	Subclass	Translation	
						Yes	No
CIS CIS	07-161634	06/23/1995	Japan			Abstract	
	07-321339	12/08/1995	Japan			Abstract	
	07-131034	05/19/1995	Japan			Abstract	

Specification and Drawings for Patent Application Serial No. 09/610,637, "Laser Irradiation Apparatus, Laser Irradiation Method, Semiconductor Device, and Method of Manufacturing a Semiconductor Device".

Examiner

Date Considered

*EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

Form PTO-1449
(Rev. 8-83)Department of Commerce
Patent and Trademark Office

Atty Docket 0756-2351

Serial No. 09/932,935

INFORMATION DISCLOSURE STATEMENT

Applicants: Shunpei YAMAZAKI et al.

Filing Date: August 21, 2001

Group Art Unit: 2812

U.S. PATENT DOCUMENTS

Examiner Initial	Document Number	Date	Name	Class	Subclass	Filing Date (if appropriate)
<i>[Signature]</i>	4,599,133	07/08/1986	Miyao et al.			

Examiner

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AC	4,609,407	09/02/1986	Masao et al.			
AC	5,432,122	07/11/1995	Chae			
AC	5,612,251	03/18/1997	Lee			
AC	5,643,801	07/01/1997	Ishihara et al.			
AC	5,972,742	10/26/1999	Zhang et al.			
AC	6,088,379	07/11/2000	Owa et al.			

FOREIGN PATENT DOCUMENTS

Examiner Initial	Document Number	Date	Country	Class	Subclass	Translation Yes No
AC	09-260676	10/03/1997	JP			Eng Abst
AC	56-064480	06/01/1981	JP			Eng Abst

OTHER DOCUMENT (Including Author, Title, Date, Pertinent Pages, Etc.)

Examiner Initial	
AC	Helen et al., "Reproducible High Field Effect Mobility Polysilicon Thin Film Transistors Involving Pulsed Nd: YVO4 Laser Crystallization", pp. 297-300, 1999, IEDM 0-7803-5410-9/99 IEEE

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01/23/2002

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<i>[Signature]</i>	4,599,133	07/08/1986	Miyao et al.			

Examiner

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9/29/02

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INFORMATION DISCLOSURE STATEMENT

Applicants: Shunpei YAMAZAKI et al.

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<i>RE</i>	4,599,133	07/08/1986	Miyao et al.			

Examiner

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Group: 28

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(Rev. 8-83)U.S. Department of Commerce
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Atty Docket 0756-2351

Serial No. 09/932,935

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AC	5,432,122	07/11/1995	Chae			
AC	5,612,251	03/18/1997	Lee			
AC	5,643,801	07/01/1997	Ishihara et al.			
AC	5,972,742	10/26/1999	Zhang et al.			
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OTHER DOCUMENT

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09/774,637

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1/08/04

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Substitute for form 1449A/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT <i>(use as many sheets as necessary)</i>				Complete if Known Application Number 09/932,935 Filing Date August 21, 2001 First Named Inventor Shunpei YAMAZAKI et al. Group Art Unit 2812 Examiner Name V. Simkovic	
Sheet	1	of	1	Attorney Docket Number 0756-2351	

[illegible][illegible]

OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS		NO.	DATE
Examiner Initials*	Cite No.†	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	
AC		Cover page of Helen et al., "Reproducible High Field Effect Mobility Polysilicon Thin Film Transistors Involved Pulsed Nd:YVO ₄ Laser Crystallization," pp. 297-300, IEDM 1999, 7803-5410-9/99 IEEE, December 5-8, 1999.	2003

Examiner Signature	<i>[Signature]</i>	Date Considered	1/08/04
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¹ Unique citation designation number. ² See attached Kinds of U.S. Patent Documents. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. ⁶ Applicant is to place a check mark here if English language Translation is attached.

¹ Unique citation designation number. ² Applicant is to place a check mark here if English language Translation is attached.

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